

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L2	4	"9913692"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/02 07:05
L3	1	09/508034.app.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/02 07:33
L4	1	09/508034.app. and interface	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/02 07:33
L5	1	09/508034.app. and semiconductive	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/02 07:54
L6	1032151	transistor	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/02 09:01
L7	4432513	polymer or resin	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/02 09:01
L8	22519	self adj assembly or self adj assembling or self adj organizing or self adj organization or selfassembly or selfassembling or selforganizing or selforganization	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/02 09:03

L9	2343	6 and 7 and 8	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/02 09:03
L10	6103	top near1 gate and bottom near1 gate	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/02 09:03
L11	76	9 and 10	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/02 09:04
L12	1975	6 and 7 and 8 and solution	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/02 09:04
L13	129	6 and 7 and 8 and solution and top adj gate	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/02 09:05
L14	1248	phase adj separation and transistor and (polymer or resin)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/02 09:06
L15	145	phase adj separation and transistor and (polymer or resin) and 8	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/02 09:06
L16	15688	transistor and (top near1 gate or bottom near1 gate)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/02 09:27
L17	5554	7 and 16	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/02 09:27

L18	182	8 and 17	US-PGPUB; USPAT; USOCR; FPPS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/02 09:28
L19	149801	siloxane or perfluoroalkyl or perfluoroarylene adj ether or perfluoroalkylene adj ether	US-PGPUB; USPAT; USOCR; FPPS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/02 09:36
L20	1812	8 and 19	US-PGPUB; USPAT; USOCR; FPPS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/02 09:36
L21	409	6 and 20	US-PGPUB; USPAT; USOCR; FPPS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/02 09:36
L23	5386	transistor and (top near1 gate and bottom near1 gate)	US-PGPUB; USPAT; USOCR; FPPS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/02 09:41
L24	31	14 and 23	US-PGPUB; USPAT; USOCR; FPPS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/02 09:41
L25	0	(10/483231).APP.	USPAT; USOCR	OR	ON	2009/04/02 09:45
L26	0	WO/2003/007397	USPAT; USOCR	OR	ON	2009/04/02 09:46
L27	6	"2003007397"	US-PGPUB; USPAT; USOCR; FPPS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/02 09:47
L28	4	"03007397"	US-PGPUB; USPAT; USOCR; FPPS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/02 09:47

L29	2	"0307397"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/02 09:49
L30	43	"037397"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/02 09:49
L31	4	"03007397"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/02 09:49
L32	2	"5981970".pn.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/02 09:50
L33	2	"7037767".pn.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/02 09:52
L45	0	"5981970".pn. and phototransistor	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/02 10:12
L46	1	10/566984.app. and phototransistor	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/02 10:12
L47	9999	photo adj transistor	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/02 10:13
L48	2	photo adj transistor and polymer and top adj gate	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/02 10:13

L49	490	photo adj transistor and polymer	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/02 10:13
L50	0	"20020084504" and siloxane	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/02 10:23
L51	740	oled and siloxane	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/02 10:27
L52	43	oled and siloxane and 8	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/02 10:28
L53	2	"5834100".pn.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/02 10:28
L54	138	polymer and top adj gate and 8	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/02 10:34
L55	1393	438/99.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/02 10:47
L56	2140	438/780.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/02 10:47
L57	16	((LAY-LAY) near2 (CHUA)). INV.	US-PGPUB; USPAT; USOCR	OR	ON	2009/04/02 10:48
L58	145	((PETER) near2 (HO)). INV.	US-PGPUB; USPAT; USOCR	OR	ON	2009/04/02 10:48

L59	49	((HENNING) near2 (SIFRINGHAUS)).INV.	US-PGPUB; USPAT; USOCR	OR	ON	2009/04/02 10:48
L60	106	((RICHARD) near2 (FRIEND)).INV.	US-PGPUB; USPAT; USOCR	OR	ON	2009/04/02 10:48
L61	2	"5981970".pn.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/02 10:49
L62	689	438/782.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/02 10:50
L63	765	438/781.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/02 10:50
L65	383	438/82.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/02 10:52
L66	141	438/for.135.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/02 10:52
L67	193	(gold with resin) same hardness	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/02 11:17

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